



Agilent Technologies

RF Balanced Device Characterization

January 15th, 2002

See the later presentations done

Jan 14, 2003 and Jan 23, 2003

www.agilent.com/find/rfbalance

presented by:

Greg Amorese

RF Balanced Device Characterization

Agenda

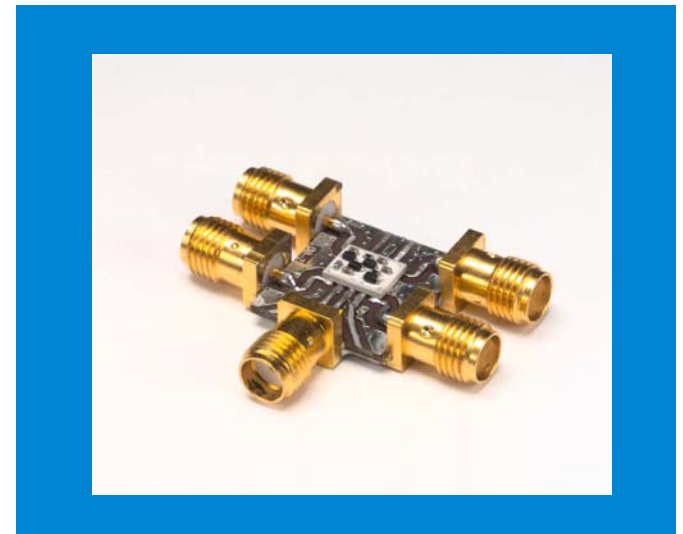
- ***Balanced Device Overview***
- **Measurement Alternatives**
- **Mixed-Mode S-parameters**
- **Balanced Circuit Design Methodology**
- **Solution Overview**
- **Calibration**
- **Measurement Examples**
- **Conclusion**



RF Balanced Device Characterization

Balanced Device Market Situation

- **Many devices for both RF design and high-speed digital applications**
- **Major benefits**
 - **High noise immunity**
 - **Low radiated noise**
 - **High density**
 - **Lower power consumption**
- **Technology used in new LTCC modules**



RF Balanced Device Characterization

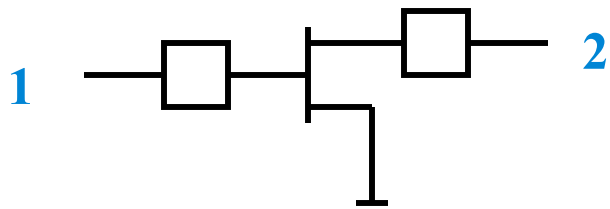
Device Evaluation Challenges

- **Measurement tools are mostly unbalanced**
- **Traditional S-parameters provide limited insight into devices actual behavior**
- **No balanced VNA calibration standards**
- **No balanced RF connector standards**
- **No standard reference impedance (Z_0) for balanced devices**



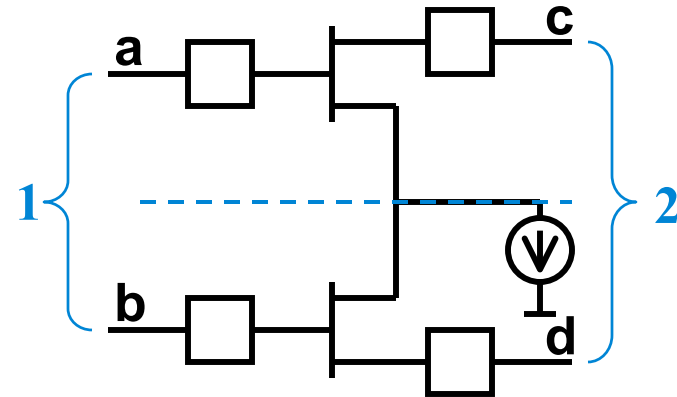
RF Balanced Device Characterization

Differential Device Topology



Unbalanced Device

- **Signals referenced to ground**



Differential Device

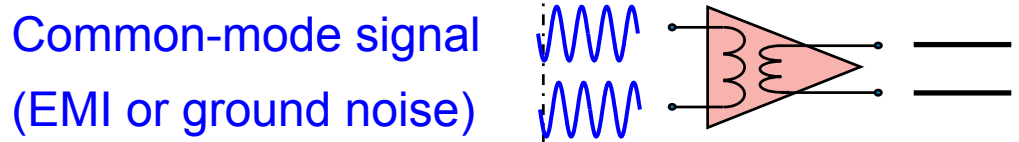
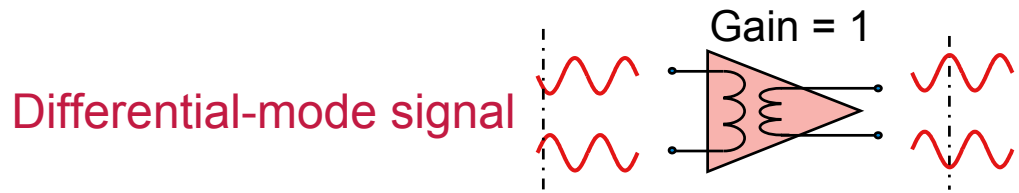
- **Signals equal amplitude and anti-phase**
- **Also supports a common mode (in-phase) signal**
- **Virtual ground**



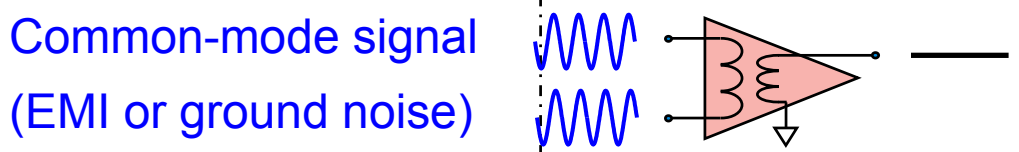
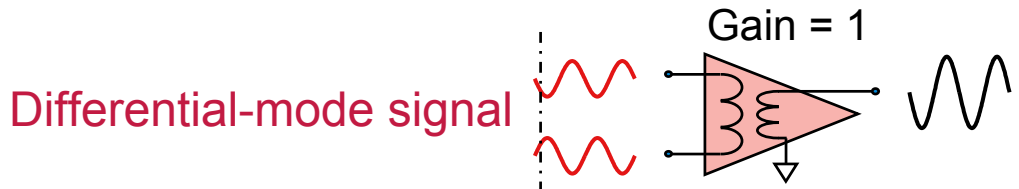
RF Balanced Device Characterization

Ideal Balanced Device Characteristics

Ideally, respond to differential and reject common-mode signals



Fully balanced

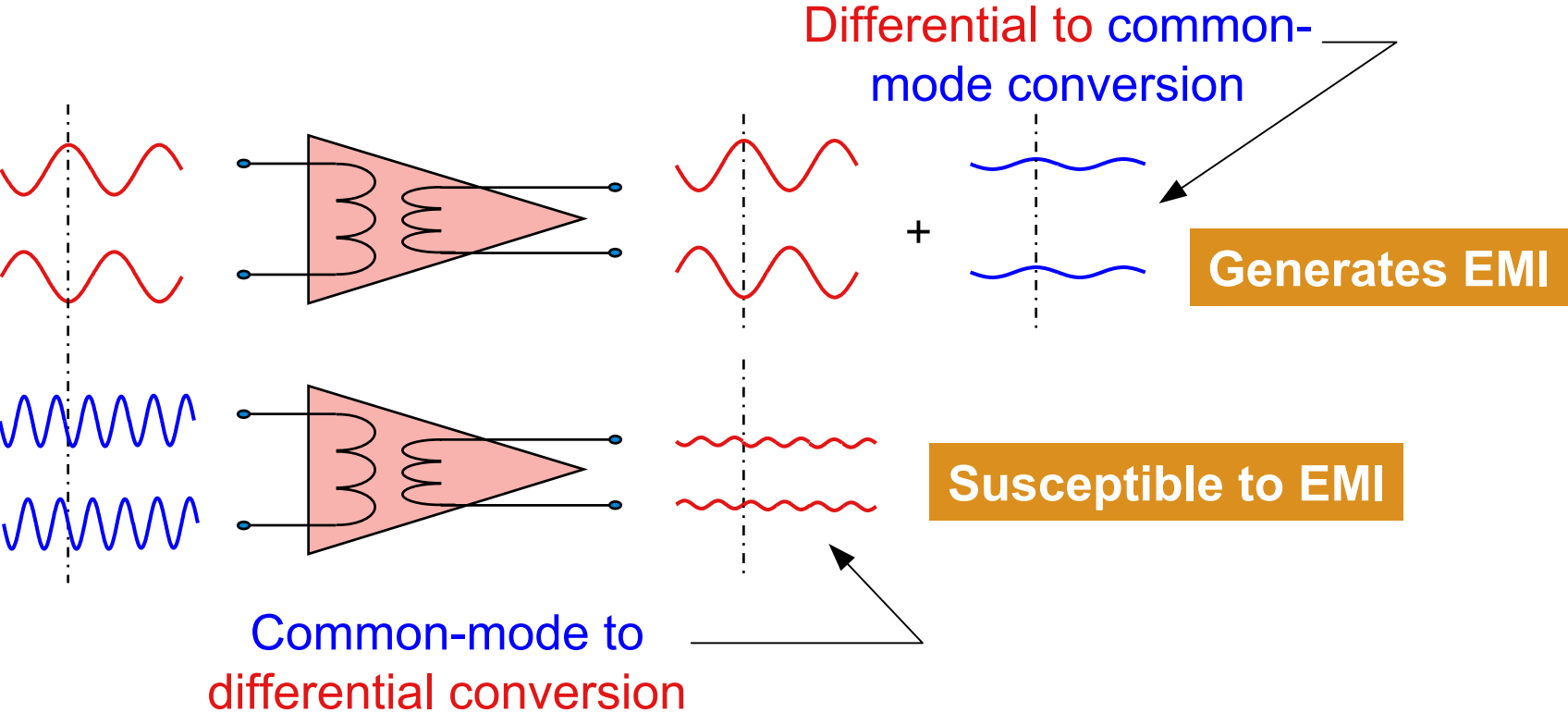


Balanced to single ended

RF Balanced Device Characterization

What About Non-Ideal Balanced Devices?

Mode conversions occur...



RF Balanced Device Characterization

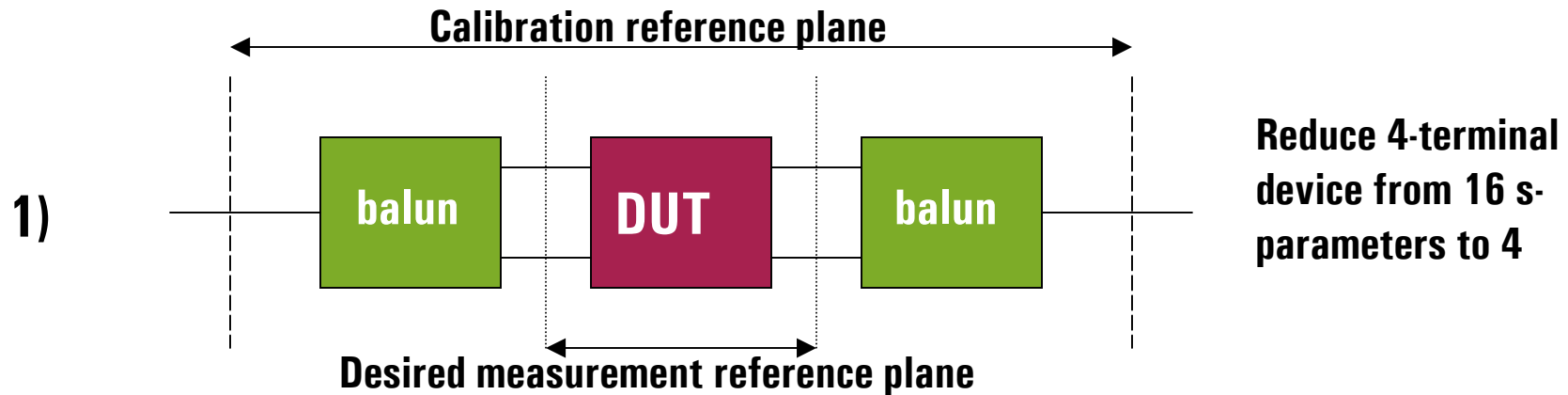
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RF Balanced Device Characterization

Measurement Alternatives



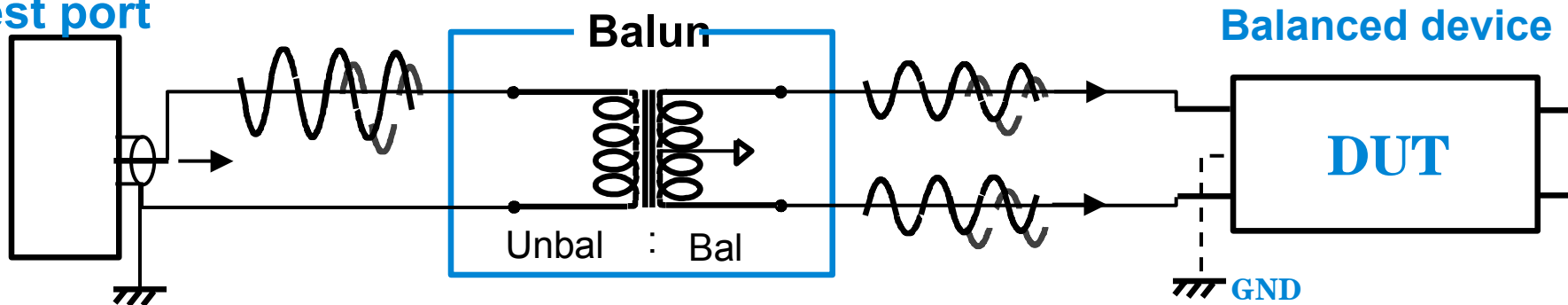
RF Balanced Device Characterization

Mode Conversion

(Unbalance \leq \geq Balance)

Need **BALUN** (BALanced/UNbalanced) transformer

Unbalanced
test port



BALUN transformer is **NOT** an ideal test bridge

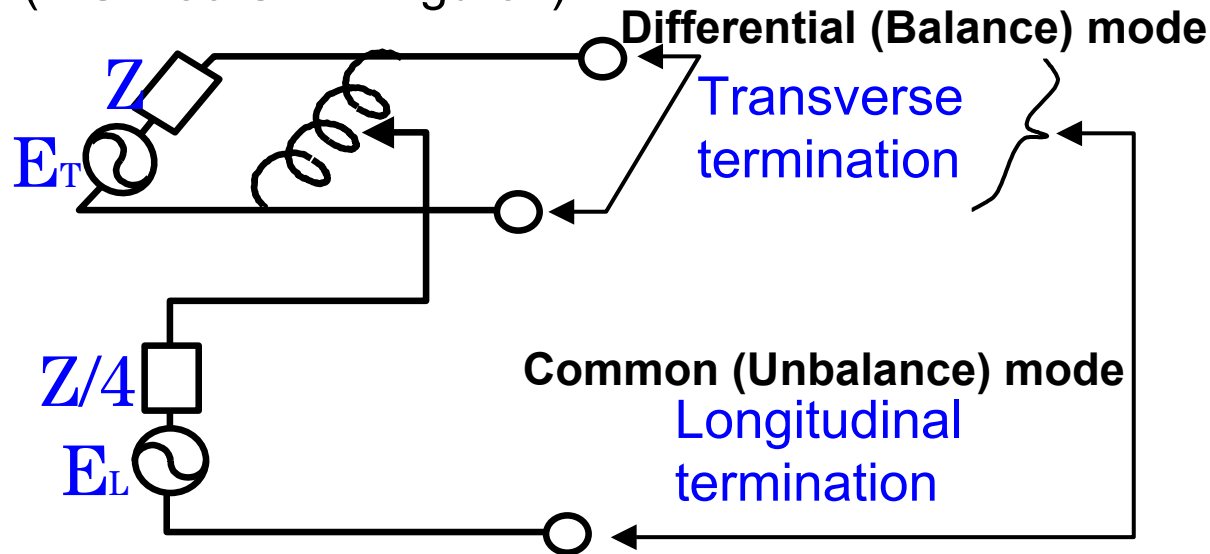


RF Balanced Device Characterization

Definition

Ideal test bridge

(ITU Rec.G117 Figure1)



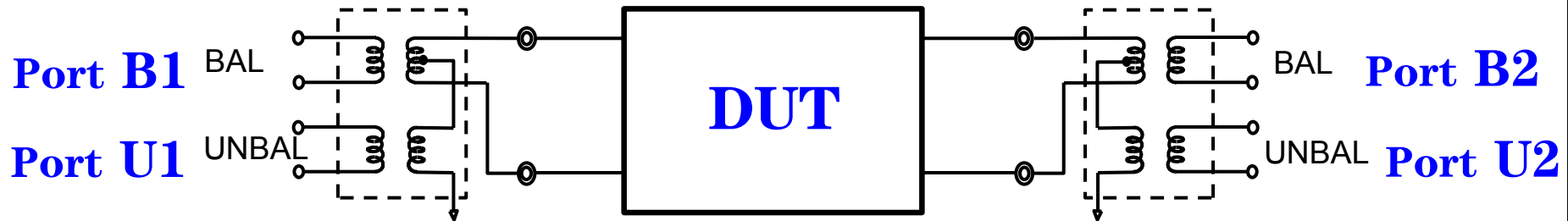
ITU Rec.G117 Figure1

Ideal test bridge : lossless infinite-inductance center-tapped coils



RF Balanced Device Characterization

Balanced Device Test Parameters



Characteristic Impedance (Z_c) : [Balanced], [Unbalanced]

Input Impedance (Z_{in}) : [Balanced], [Unbalanced]

Insertion Loss (Attenuation) : SB2B1 [Balanced], SU2U1 [Unbalanced]

Return Loss : SB1B1 [Balanced], SU1U1 [Unbalanced]

Conversion Loss , Rejection Ratio : (Balance to Unbalance Parameters)

TCTL (Transverse Conversion Transfer Loss) : SU2B1

LCTL (Longitudinal Conversion Transfer Loss) : SB2U1

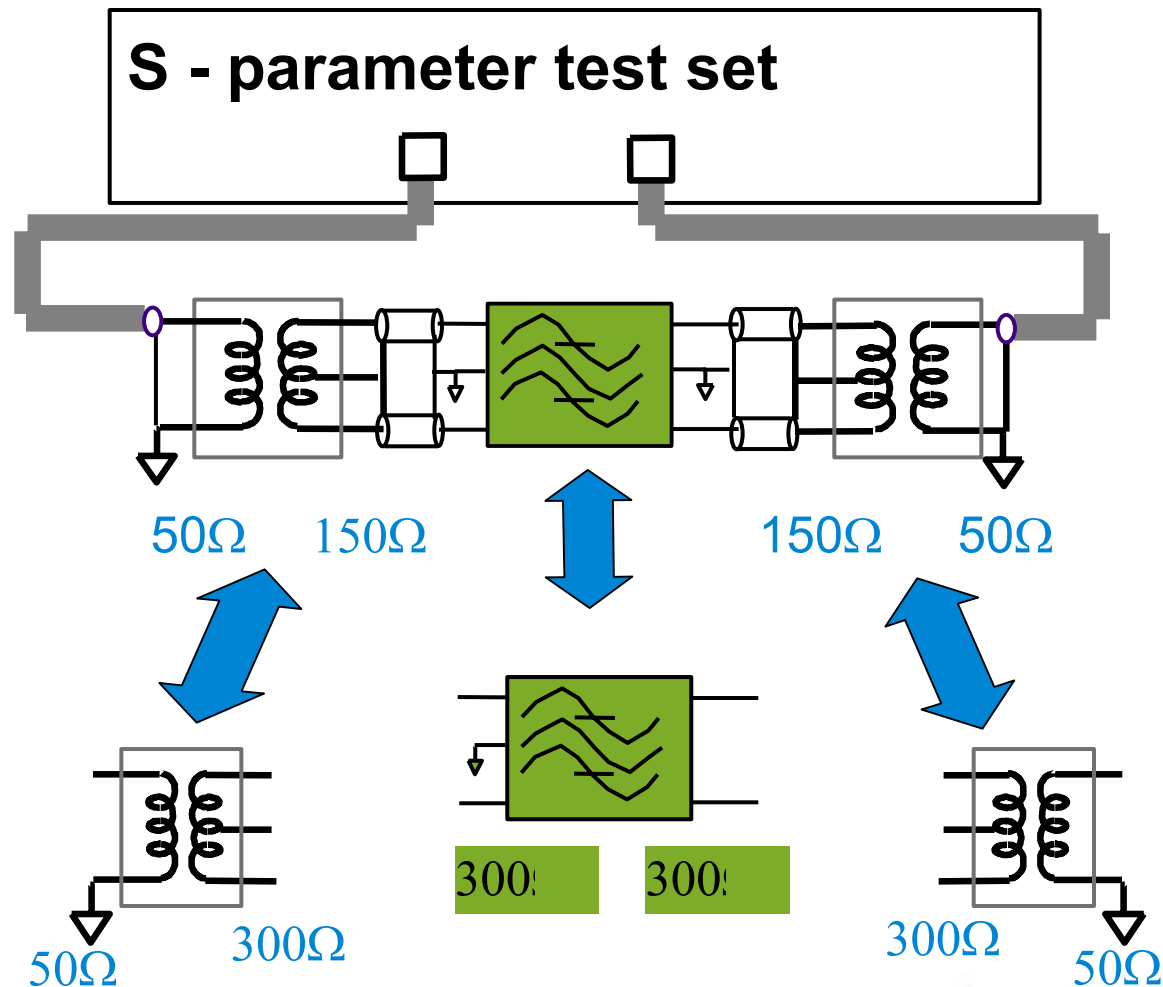
LCL (Longitudinal Conversion Loss) : SB1U1

CMRR (Common Mode Rejection Ratio)



RF Balanced Device Characterization

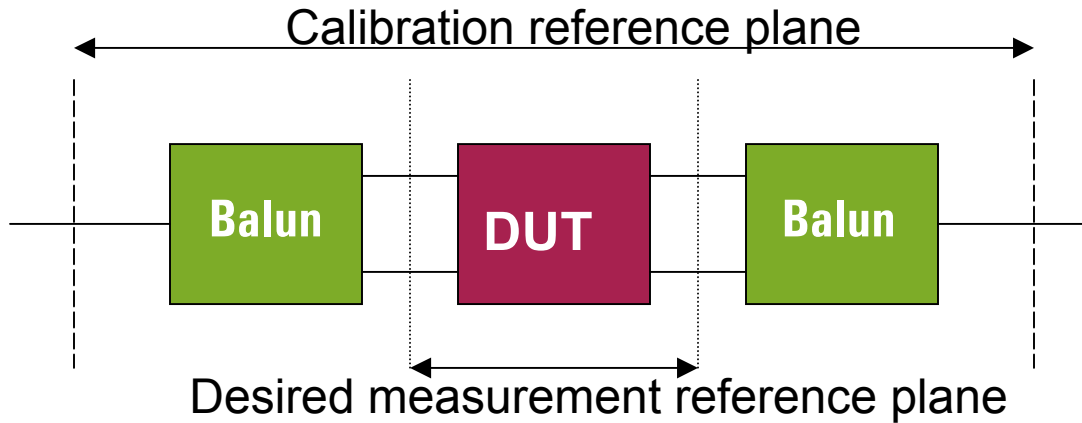
Calibration using Baluns



RF Balanced Device Characterization

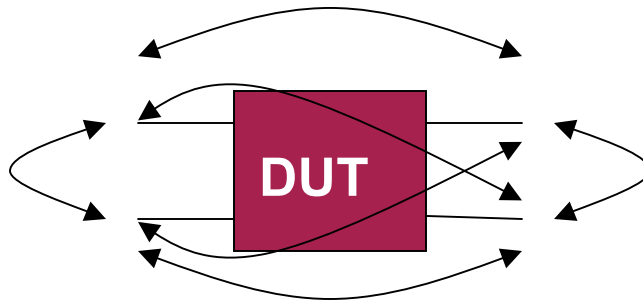
Measurement Alternatives

1)



Reduce 4-terminal device from 16 s-parameters to 4

2)

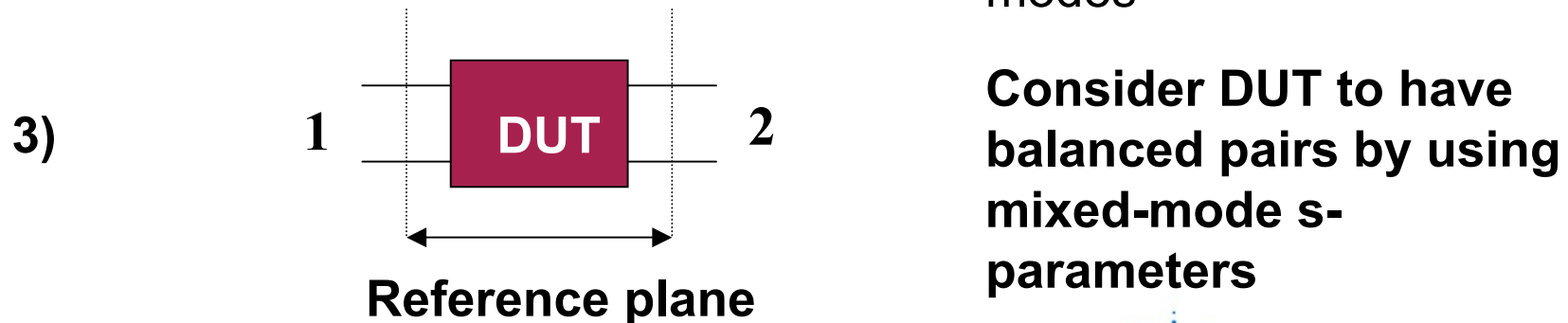
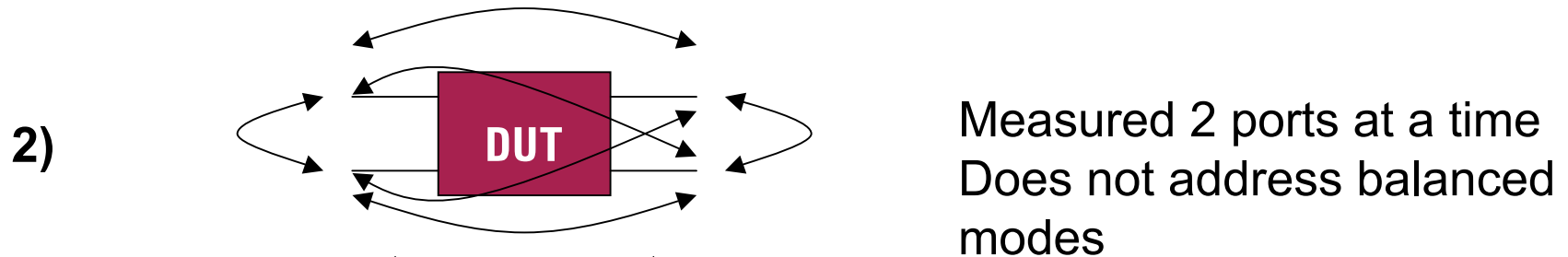
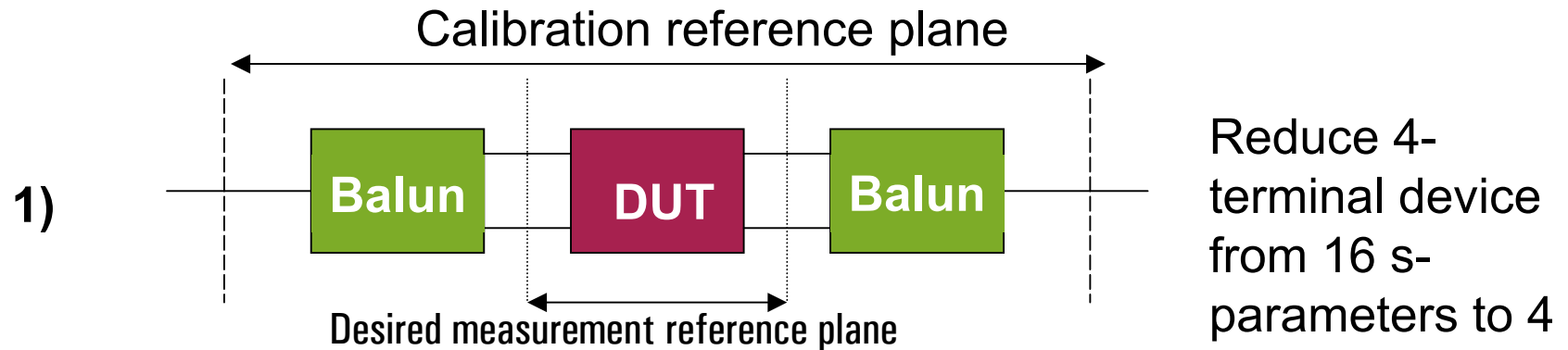


Measured 2 ports at a time
Does not address balanced modes



RF Balanced Device Characterization

Measurement Alternatives



RF Balanced Device Characterization

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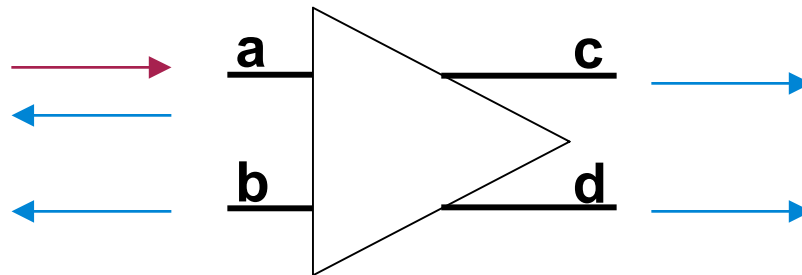


RF Balanced Device Characterization

Single-Ended S-Parameters

Conventional S-parameters answer the question ...

If a single port of a device is **stimulated**,
what are the corresponding **responses** on all
ports of the device?



RF Balanced Device Characterization

Single-Ended S-Parameter Review

Single-ended 4-port



Voltage V_n
Current I_n
Impedance $Z_n = V_n^+ / I_n^+$

	Normalized power waves
stimulus	$a_n = \frac{1}{2 \cdot \sqrt{\text{Re} \{Z_n\}}} (V_n + I_n \cdot Z_n)$
response	$b_n = \frac{1}{2 \cdot \sqrt{\text{Re} \{Z_n\}}} (V_n - I_n \cdot Z_n)$

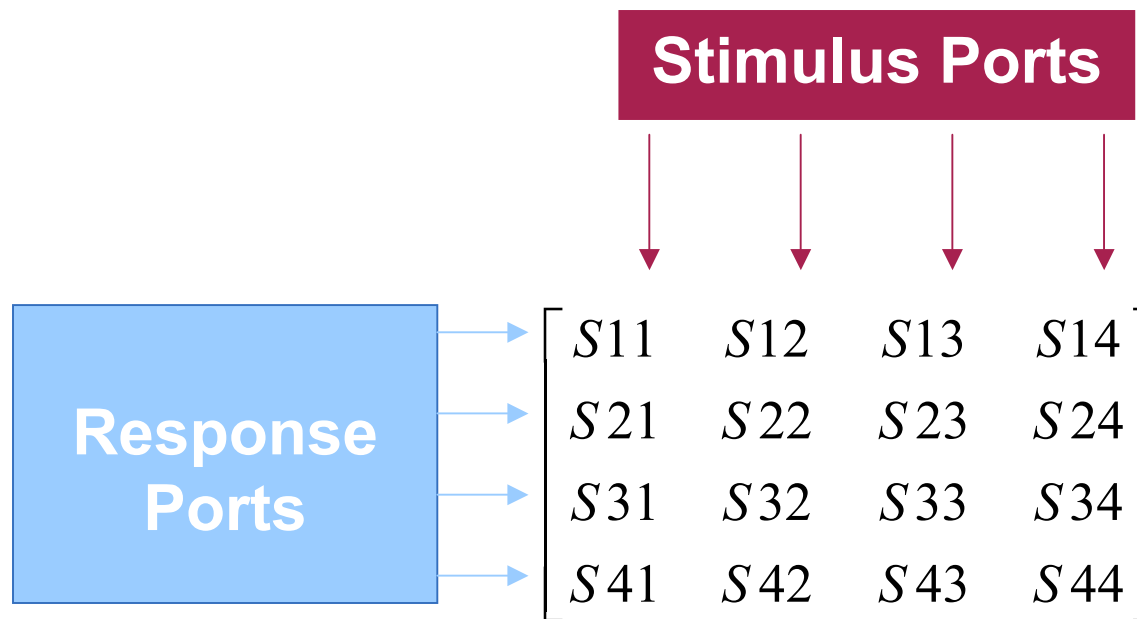
$$S = b/a$$



RF Balanced Device Characterization

Single-Ended S-Matrix

$$S = b/a$$

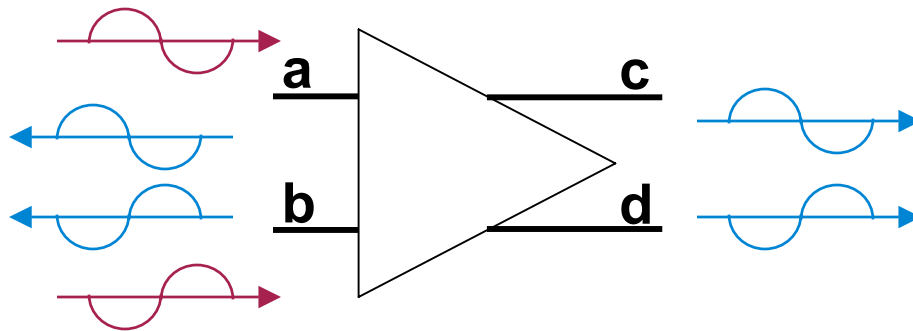


RF Balanced Device Characterization

Mixed-Mode S-Parameters

Mixed-mode S-parameters answer the question ...

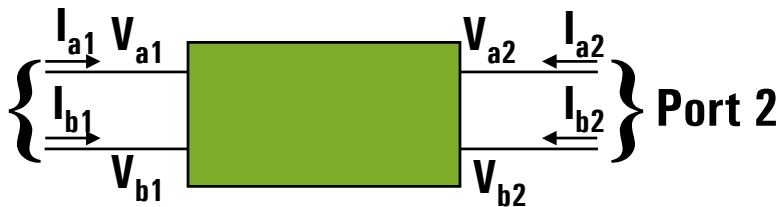
If a balanced port of a device is **stimulated** with a common-mode or differential-mode signal, what are the corresponding common-mode and differential-mode **responses** on all ports of the device?



RF Balanced Device Characterization

Mixed-Mode S-Parameters

Balanced 2-Port



	Differential	Common
Voltage	$V_{an} - V_{bn}$	$0.5 * (V_{an} + V_{bn})$
Current	$0.5 * (I_{an} - I_{bn})$	$I_{an} + I_{bn}$
Impedance	$Z_{Dn} = V_D^+ / I_D^+$	$Z_{Cn} = V_C^+ / I_C^+$

	Normalized Power Waves	
	Differential-Mode	Common-Mode
stimulus		
response		

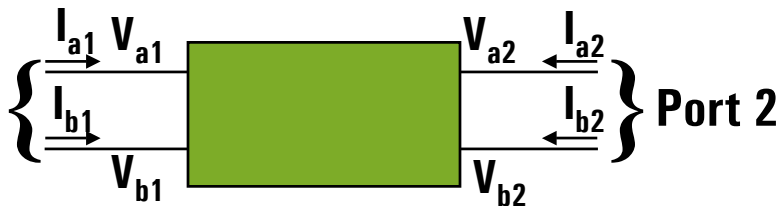
$$S = b/a$$



RF Balanced Device Characterization

Mixed-Mode S-Parameters

Balanced 2-Port



	Differential	Common
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Current	$0.5 * (I_{an} - I_{bn})$	$I_{an} + I_{bn}$
Impedance	$Z_{Dn} = V_D^+ / I_D^+$	$Z_{Cn} = V_C^+ / I_C^+$

	Normalized Power Waves	
	Differential-Mode	Common-Mode
stimulus	$a_{dn} = \frac{1}{2 \cdot \sqrt{\text{Re} \{Z_{dn}\}}} (V_{dn} + I_{dn} \cdot Z_{dn})$	$a_{cn} = \frac{1}{2 \cdot \sqrt{\text{Re} \{Z_{cn}\}}} (V_{cn} + I_{cn} \cdot Z_{cn})$
response		

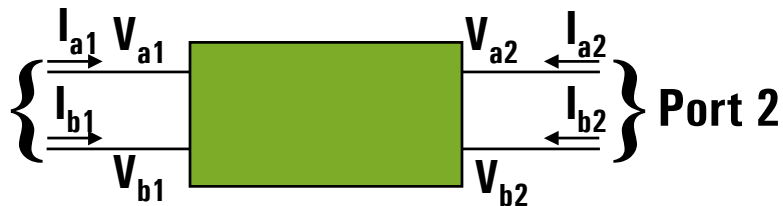
S = b/a



RF Balanced Device Characterization

Mixed-Mode S-Parameters

Balanced 2-Port



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Voltage	$V_{an} - V_{bn}$	$0.5 * (V_{an} + V_{bn})$
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Impedance	$Z_{Dn} = V_D^+ / I_D^+$	$Z_{Cn} = V_C^+ / I_C^+$

	Normalized Power Waves	
	Differential-Mode	Common-Mode
stimulus	$a_{dn} = \frac{1}{2 \cdot \sqrt{\text{Re}\{Z_{dn}\}}} (V_{dn} + I_{dn} \cdot Z_{dn})$	$a_{cn} = \frac{1}{2 \cdot \sqrt{\text{Re}\{Z_{cn}\}}} (V_{cn} + I_{cn} \cdot Z_{cn})$
response	$b_{dn} = \frac{1}{2 \cdot \sqrt{\text{Re}\{Z_{dn}\}}} (V_{dn} - I_{dn} \cdot Z_{dn})$	$b_{cn} = \frac{1}{2 \cdot \sqrt{\text{Re}\{Z_{cn}\}}} (V_{cn} - I_{cn} \cdot Z_{cn})$

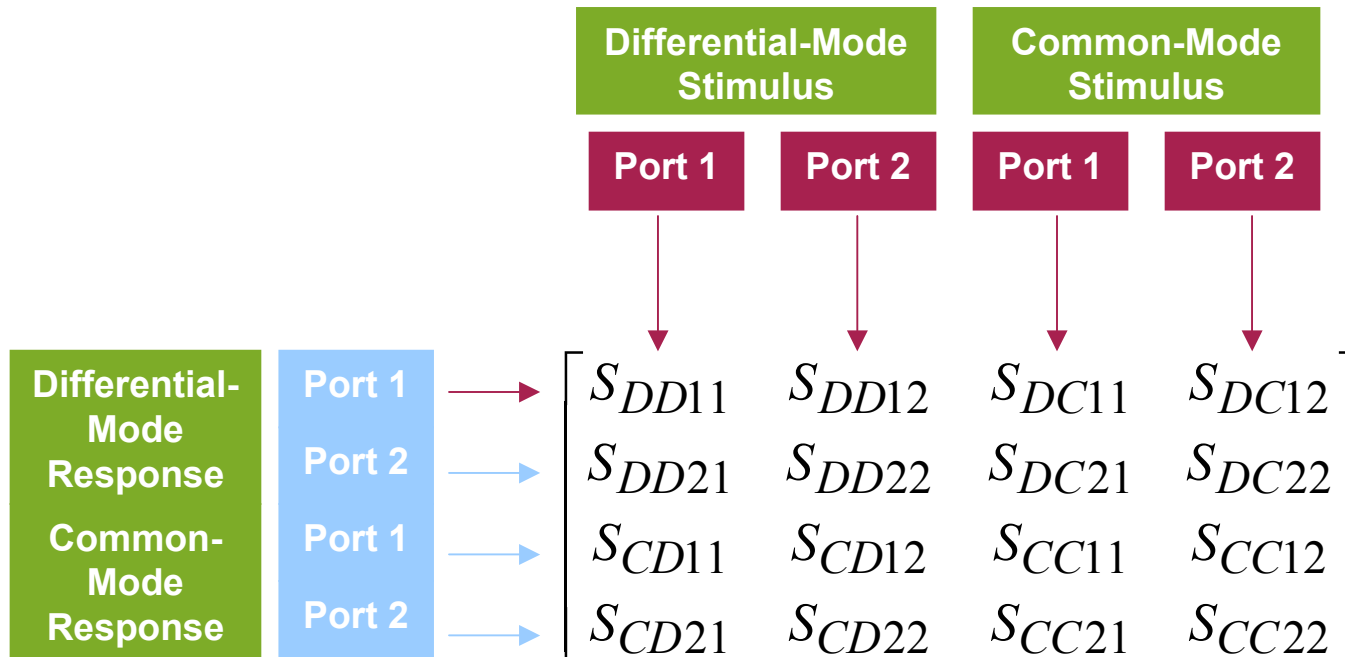
$$S = b/a$$



RF Balanced Device Characterization

Mixed-Mode S-Matrix

$$\mathbf{S} = \mathbf{b}/\mathbf{a}$$



Naming Convention: S mode res., mode stim., port res., port stim.



RF Balanced Device Characterization

Mixed-Mode S-Matrix: DD Quadrant

Input Reflection

Reverse Transmission

$$\begin{bmatrix} S_{DD\ 11} & S_{DD\ 12} & S_{DC\ 11} & S_{DC\ 12} \\ S_{DD\ 21} & S_{DD\ 22} & S_{DC\ 21} & S_{DC\ 22} \\ S_{CD\ 11} & S_{CD\ 12} & S_{CC\ 11} & S_{CC\ 12} \\ S_{CD\ 21} & S_{CD\ 22} & S_{CC\ 21} & S_{CC\ 22} \end{bmatrix}$$

Forward Transmission

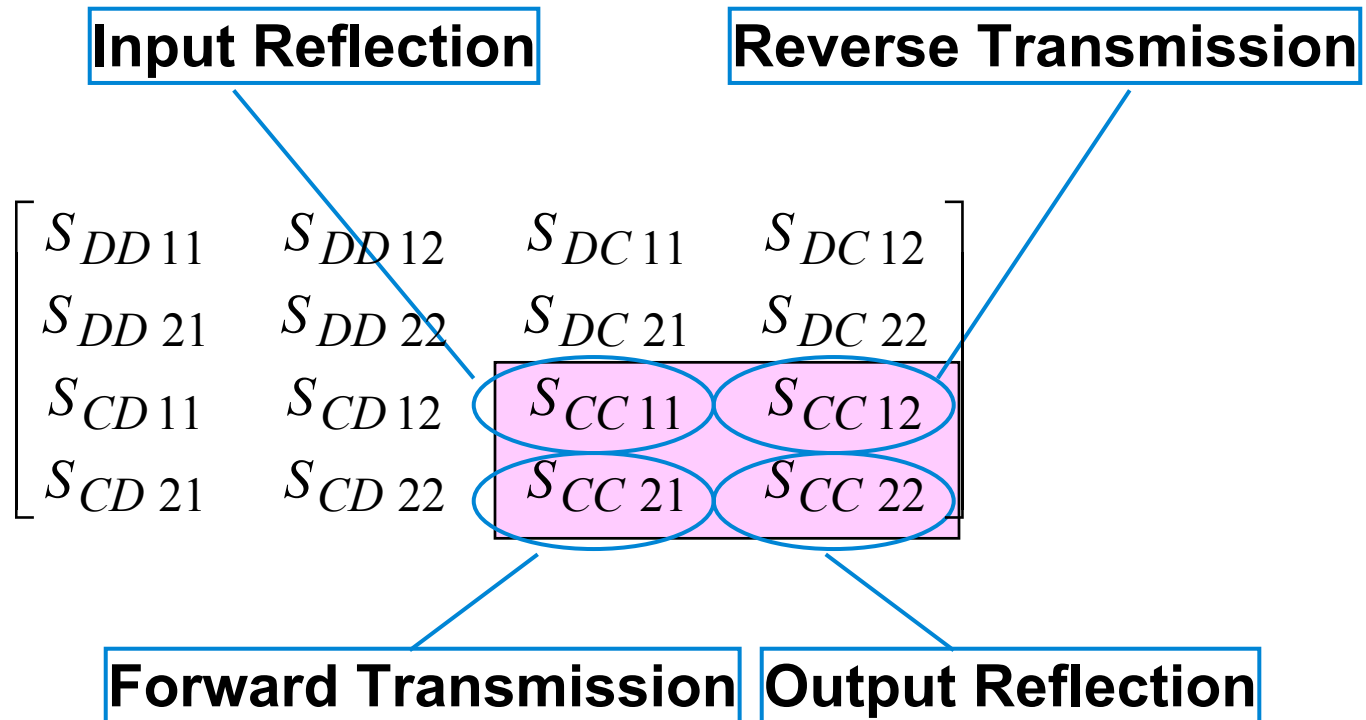
Output Reflection

Describes fundamental performance in pure differential-mode operation



RF Balanced Device Characterization

Mixed-Mode S-Matrix: CC Quadrant

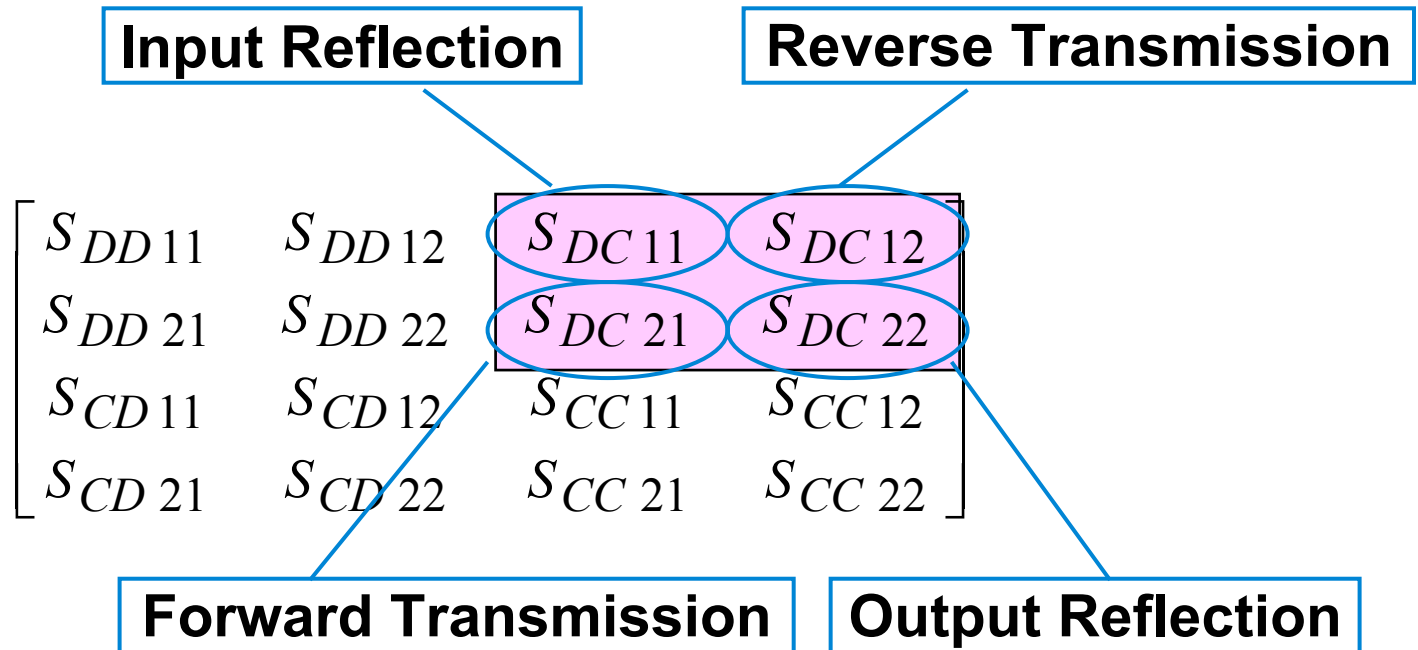


Describes fundamental performance in pure common-mode operation



RF Balanced Device Characterization

Mixed-Mode S-Matrix: DC Quadrant

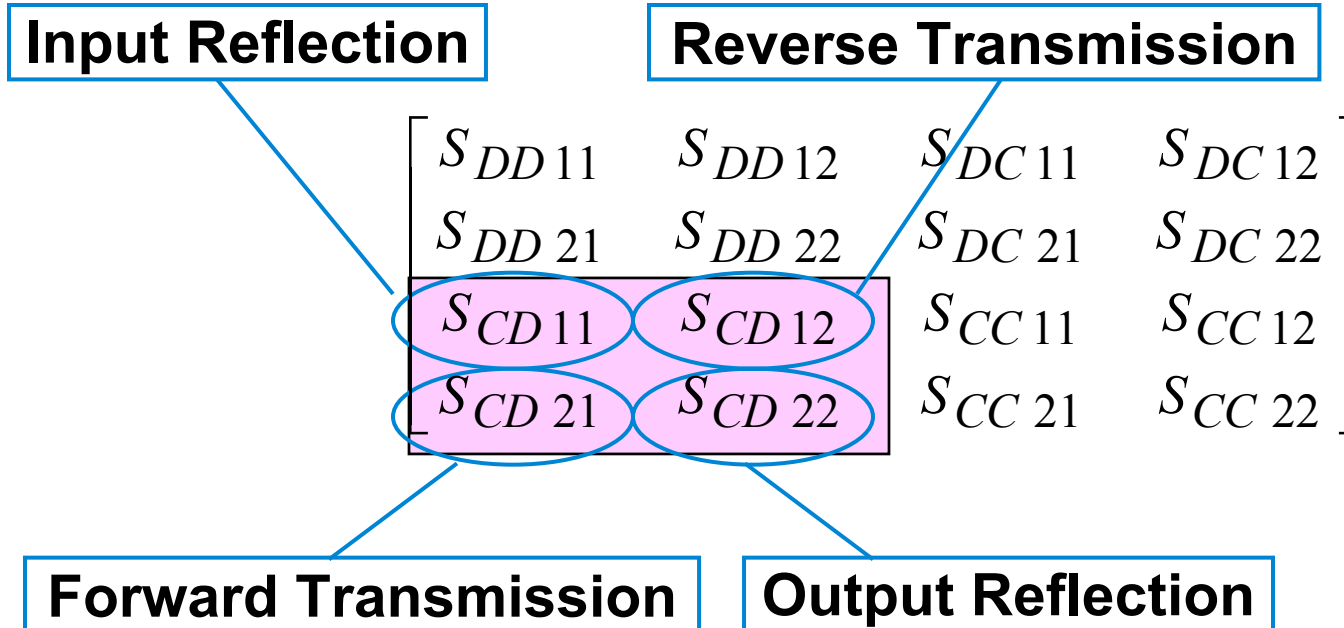


- Describes conversion of a common-mode stimulus to a differential-mode response
- Terms are ideally equal to zero with perfect symmetry
- Related to the susceptibility to EMI



RF Balanced Device Characterization

Mixed-Mode S-Matrix: CD Quadrant



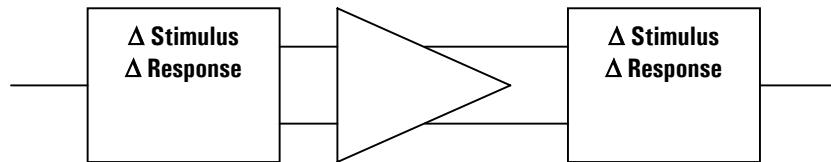
- Describes conversion of a differential-mode stimulus to a common-mode response
- Terms are ideally equal to zero with perfect symmetry
- Related to the generation of EMI



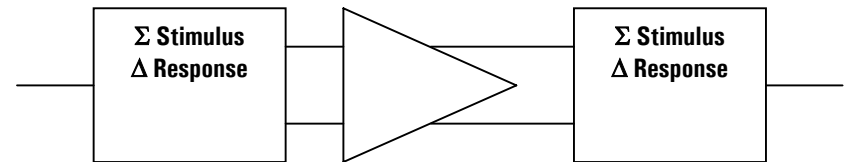
RF Balanced Device Characterization

Conceptual Hardware Networks Required to Get Mixed-Mode S-Parameters with 2-port NA

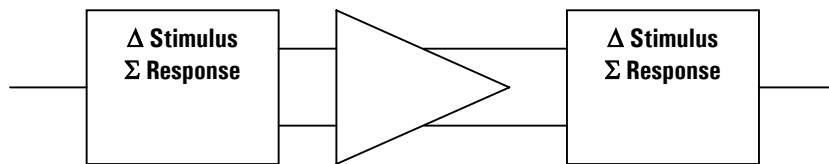
Differential Divide/Combine



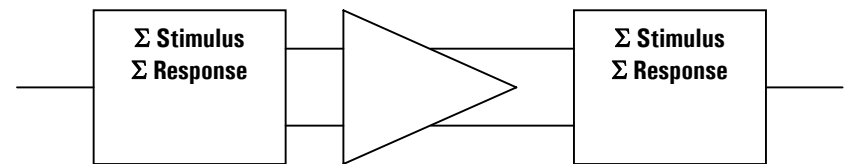
In-Phase Divide/Differential Combine



Differential Divide/In-Phase Combine



In-Phase Divide/Combine



DC and CD Quadrants would require complex hardware networks

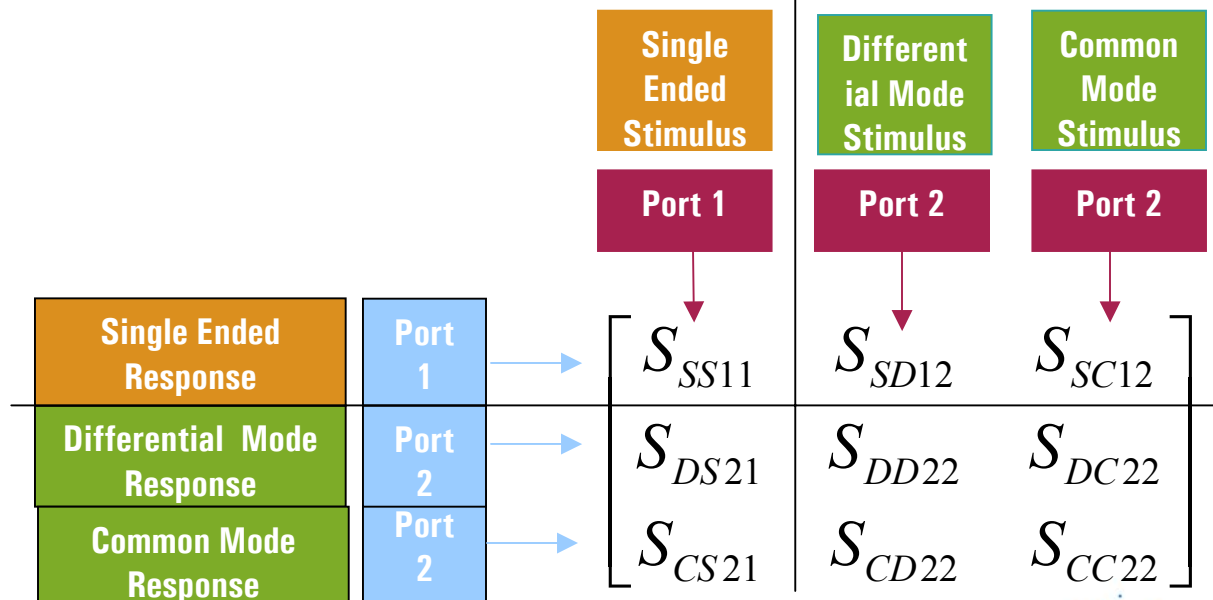
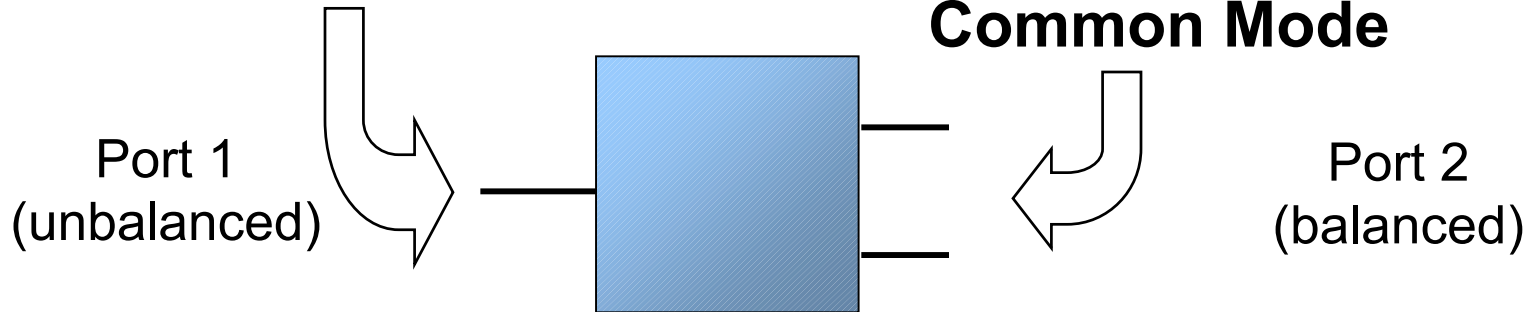


RF Balanced Device Characterization

Three-Terminal Devices

Single-Ended

Differential Mode
Common Mode



RF Balanced Device Characterization

Agenda

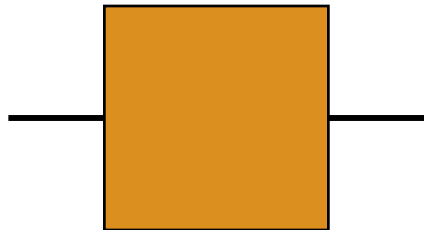
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RF Balanced Device Characterization

Brain Teaser #1

What are the simultaneous conjugate input and output matching impedances of the following circuit?



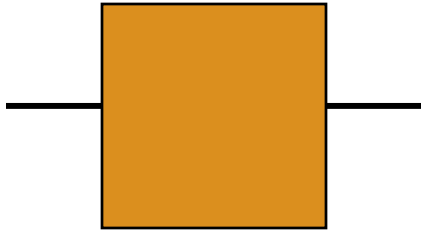
Single-ended 2-port



RF Balanced Device Characterization

Brain Teaser #1: Answers

What are the simultaneous conjugate input and output matching impedances of the following circuit?



Single-ended 2-port

Well-documented relationship between simultaneous conjugate match and s-parameters.

where:

$$B_1 = 1 - |S_{22}|^2 + |S_{11}|^2 - |D|^2$$

$$B_2 = 1 - |S_{11}|^2 + |S_{22}|^2 - |D|^2$$

$$C_1 = S_{11} - D \cdot S_{22}^*$$

$$C_2 = S_{22} - D \cdot S_{11}^*$$

$$D = S_{11} \cdot S_{22} - S_{12} \cdot S_{21}$$

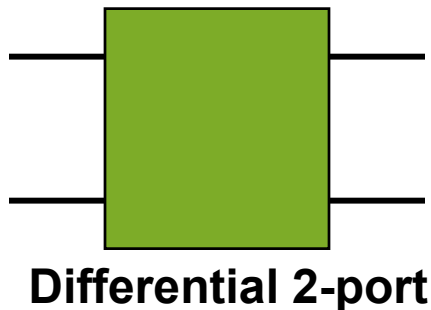
$$\Gamma_1 = \frac{C_1^*}{|C_1|} \cdot \left[\frac{B_1}{2 \cdot |C_1|} - \sqrt{\frac{B_1^2}{|2 \cdot C_1|^2} - 1} \right]$$
$$\Gamma_0 = \frac{C_2^*}{|C_2|} \cdot \left[\frac{B_2}{2 \cdot |C_2|} - \sqrt{\frac{B_2^2}{|2 \cdot C_2|^2} - 1} \right]$$



RF Balanced Device Characterization

Brain Teaser #2: Answers

What are the simultaneous conjugate input and output matching impedances of the following circuit?



Reduce performance of differential circuit to a single mode of operation using mixed-mode s-parameters, and follow same procedure as single-ended 2-port.

where:

$$B_1 = 1 - |S_{DD22}|^2 + |S_{DD11}|^2 - |D|^2$$

$$B_2 = 1 - |S_{DD11}|^2 + |S_{DD22}|^2 - |D|^2$$

$$C_1 = S_{DD11} - D \cdot S_{DD22}^*$$

$$C_2 = S_{DD22} - D \cdot S_{DD11}^*$$

$$D = S_{DD11} \cdot S_{DD22} - S_{DD12} \cdot S_{DD21}$$

$$\Gamma_1 = \frac{C_1^*}{|C_1|} \cdot \left[\frac{B_1}{2 \cdot |C_1|} - \sqrt{\frac{B_1^2}{2 \cdot |C_1|^2} - 1} \right]$$
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RF Balanced Device Characterization

Simultaneous Conjugate Match: Single-Ended vs. Differential

Single-Ended 2-Port

$$\Gamma_1 = \frac{C_1^*}{|C_1|} \cdot \left[\frac{B_1}{2 \cdot |C_1|} - \sqrt{\frac{B_1^2}{2 \cdot |C_1|^2} - 1} \right]$$
$$\Gamma_0 = \frac{C_2^*}{|C_2|} \cdot \left[\frac{B_2}{2 \cdot |C_2|} - \sqrt{\frac{B_2^2}{2 \cdot |C_2|^2} - 1} \right]$$

where:

$$B_1 = 1 - |S_{22}|^2 + |S_{11}|^2 - |D|^2$$

$$B_2 = 1 - |S_{11}|^2 + |S_{22}|^2 - |D|^2$$

$$C_1 = S_{11} - D \cdot S_{22}^*$$

$$C_2 = S_{22} - D \cdot S_{11}^*$$

$$D = S_{11} \cdot S_{22} - S_{12} \cdot S_{21}$$

Differential 2-Port

$$\Gamma_1 = \frac{C_1^*}{|C_1|} \cdot \left[\frac{B_1}{2 \cdot |C_1|} - \sqrt{\frac{B_1^2}{2 \cdot |C_1|^2} - 1} \right]$$
$$\Gamma_0 = \frac{C_2^*}{|C_2|} \cdot \left[\frac{B_2}{2 \cdot |C_2|} - \sqrt{\frac{B_2^2}{2 \cdot |C_2|^2} - 1} \right]$$

where:

$$B_1 = 1 - |S_{DD22}|^2 + |S_{DD11}|^2 - |D|^2$$

$$B_2 = 1 - |S_{DD11}|^2 + |S_{DD22}|^2 - |D|^2$$

$$C_1 = S_{DD11} - D \cdot S_{DD22}^*$$

$$C_2 = S_{DD22} - D \cdot S_{DD11}^*$$

$$D = S_{DD11} \cdot S_{DD22} - S_{DD12} \cdot S_{DD21}$$



RF Balanced Device Characterization

Balanced Device Design Methodology

- Matching example can be also be extended to other design considerations (K, MAG, VSWR, Z, etc.)
- Reason is parallel approach to parameter derivation
- For balanced device, use identical approach as single-ended design
- Isolate balanced device to specific mode
 - Substitute parameters
 - Example: ($S_{nm} \rightarrow S_{DDnm}$)



RF Balanced Device Characterization

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RF Balanced Device Characterization

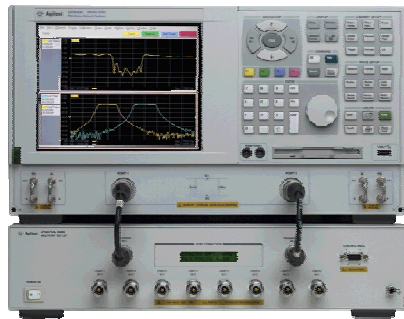
Alternative Methods to Acquire Mixed-Mode S-Parameters



- Standard 2-Port Network Analyzer

- MultiPort Network Analyzer

- MultiPort Network Analyzer with Balanced Measurement Capability



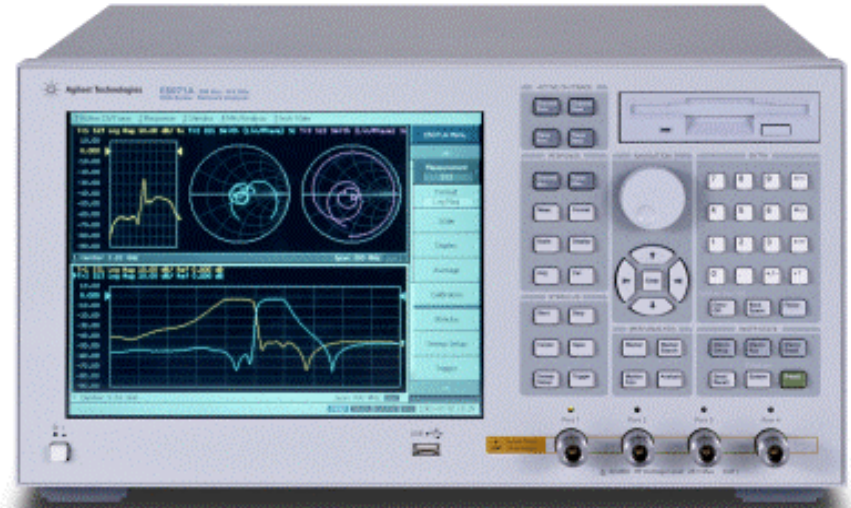
Math
(RF Circuit
Simulation
Software;
e.g.ADS)

Mixed-Mode S-Parameters



RF Balanced Device Characterization

Agilent ENA Series Differential Measurement Network Analyzer



- **Self-Contained Balanced Measurement Solution for R&D or Mfg**
- **3 GHz and 8.5 GHz Versions; Up to 4 ports**
- **High Accuracy and Very High Speed**



RF Balanced Device Characterization

4-Port Balanced Measurement System



- **Excellent R&D Solution**
- **Versions up to 20 GHz**
- **Time Domain option**
- **Agilent 8753, 8720, or PNA based solutions**



RF Balanced Device Characterization

High Speed Multiport Device Test System



- Excellent for High Port Count (e.g. LTCC) Devices
- Semi-custom Agilent PNA based Solutions
- Meets Both R&D or High-Speed Manufacturing Needs



RF Balanced Device Characterization

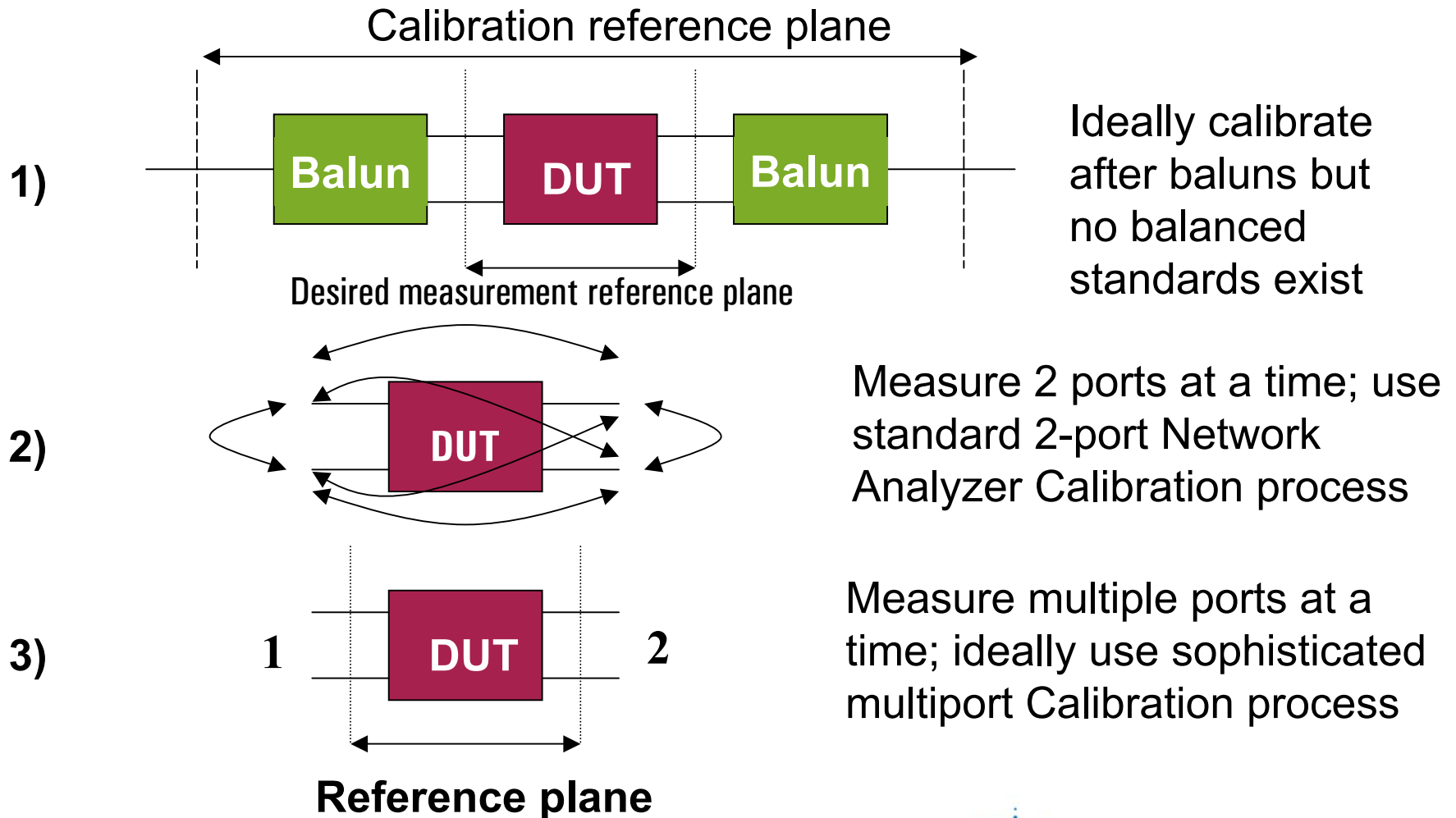
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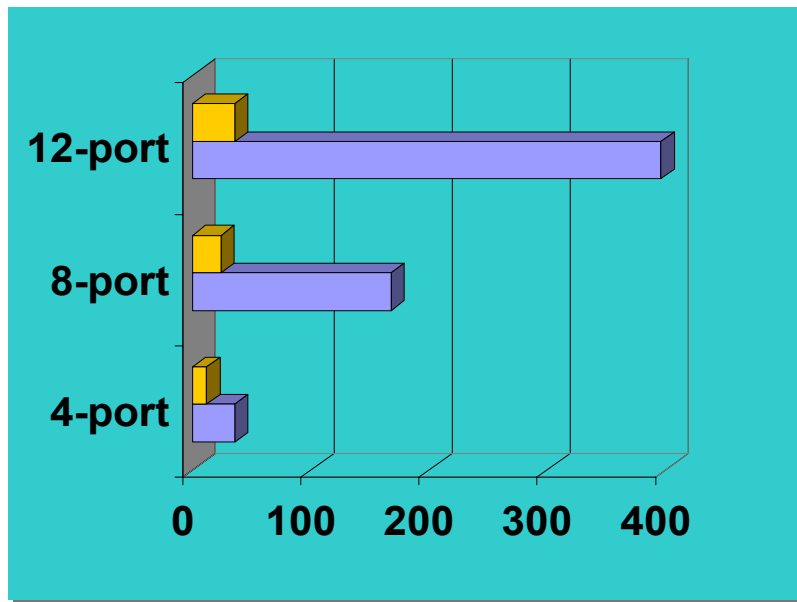
Calibration For Each Measurement Alternative



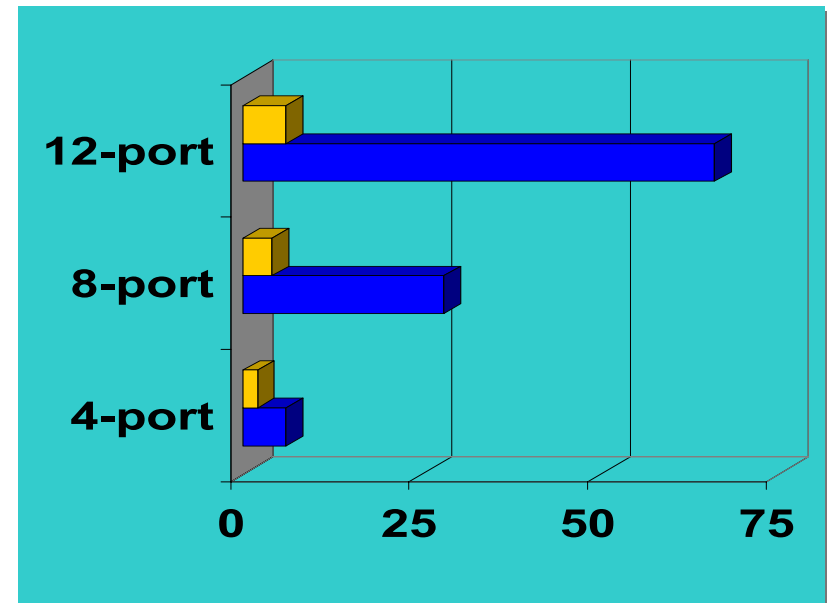
RF Balanced Device Characterization

Sophisticated Multiport Cal Eliminates Redundant Connections of Cal Standards

Reflection Connections



Through Connections



■ Sophisticated Multiport Cal

■ Traditional 2-port VNA Cal



RF Balanced Device Characterization

E-CAL (Electronic Calibration)

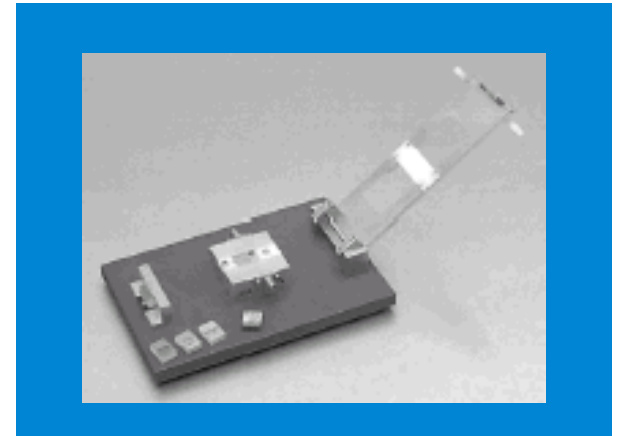
- Automated “system” for performing calibrations
- 2- and 4-port configurations
- Single connection
- Calibrates all paths/permutations
- Resulting calibration is traceable



RF Balanced Device Characterization

Fixture Calibration

- **Methods for removing fixture effects from measurement:**
 - **Port extensions**
 - **Delay**
 - **TRL calibration**
 - **In-fixture SOLT calibration**
 - **De-embedding**
 - **Soft fixturing**



RF Balanced Device Characterization

Agenda

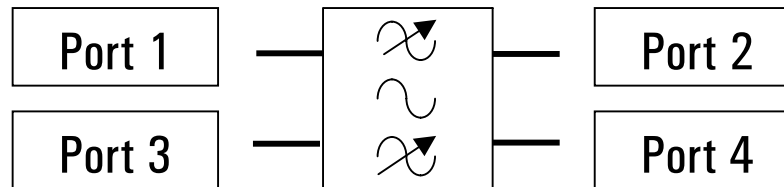
- **Balanced Device Overview**
- **Measurement Alternatives**
- **Mixed-Mode S-parameters**
- **Balanced Circuit Design Methodology**
- **Solution Overview**
- **Calibration**
- ***Measurement Examples***
- **Conclusion**



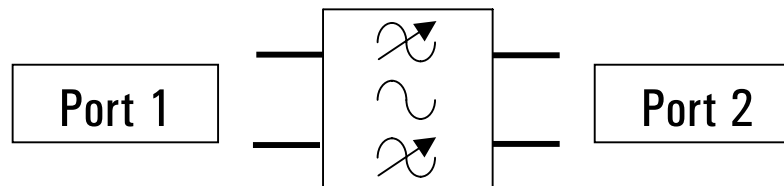
RF Balanced Device Characterization

SAW Filter Measurement Example

Single-Ended Representation (Conventional S-Parameters)

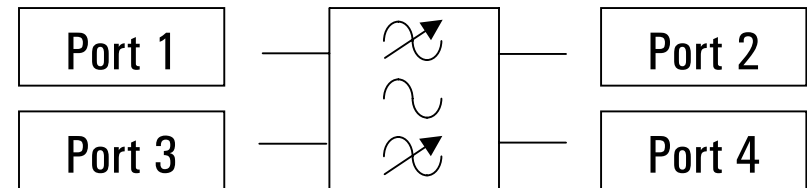
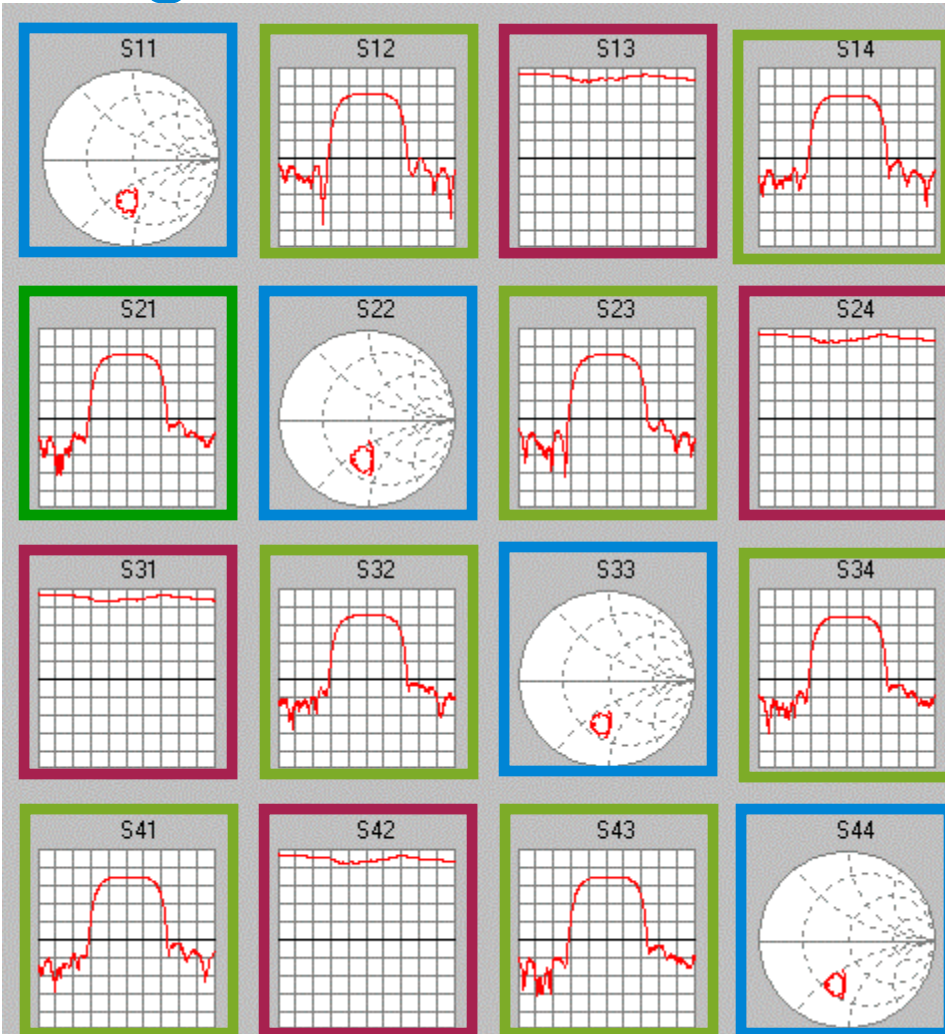


Balanced Representation (Mixed-Mode S-Parameters)



RF Balanced Device Characterization

Single-Ended SAW Filter Performance



- Reference $Z = 350\Omega$ (all ports)
- Capacitive component to port matches
- Insertion loss (14.5dB)
- Input-input coupling
- Output-output coupling



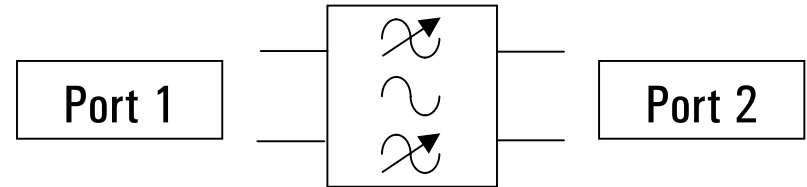
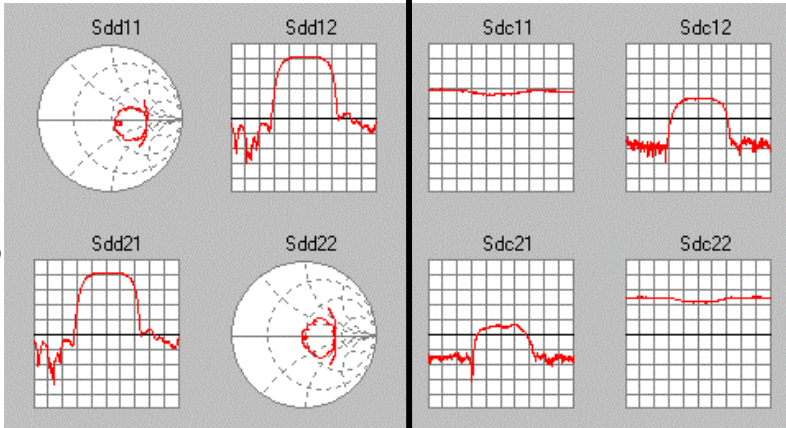
RF Balanced Device Characterization

Balanced SAW Filter Performance

Differential Stimulus
Differential Response

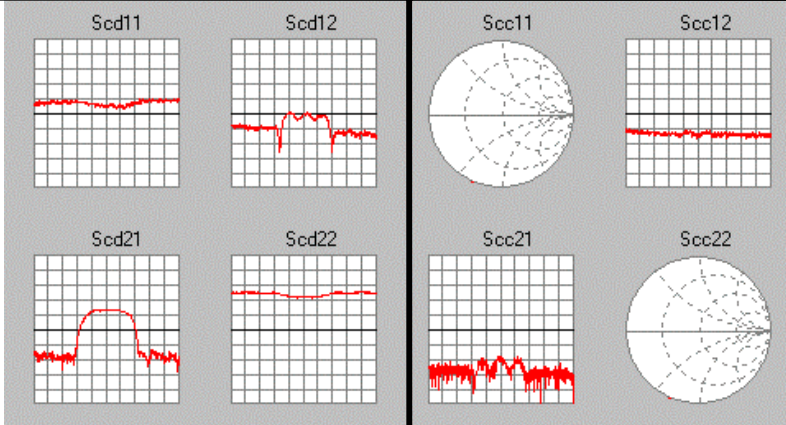
Common Stimulus
Differential Response

$Z_0 = 700 \Omega$



- Reference Z depends on mode
- Well-matched differentially
- Reflective in common mode
- Insertion loss (8.9dB)
- Mode conversion
- Common mode rejection (60dB)

$Z_0 = 175 \Omega$



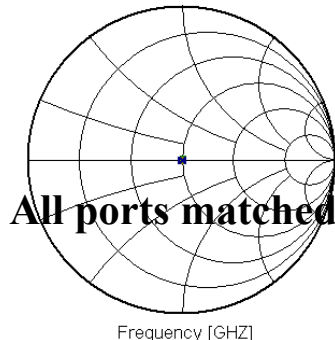
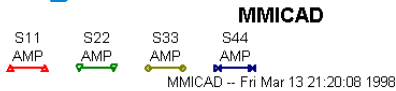
Differential Stimulus
Common Response

Common Stimulus
Common Response

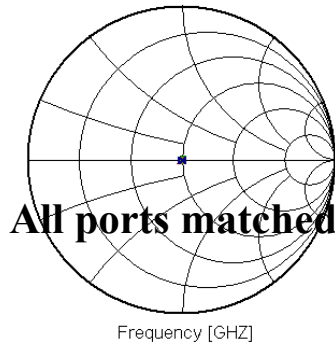
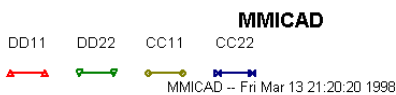
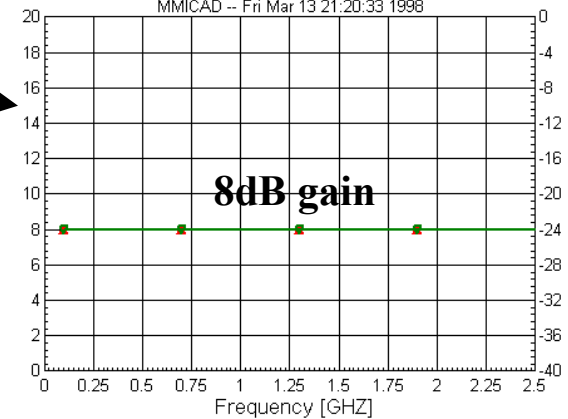


RF Balanced Device Characterization

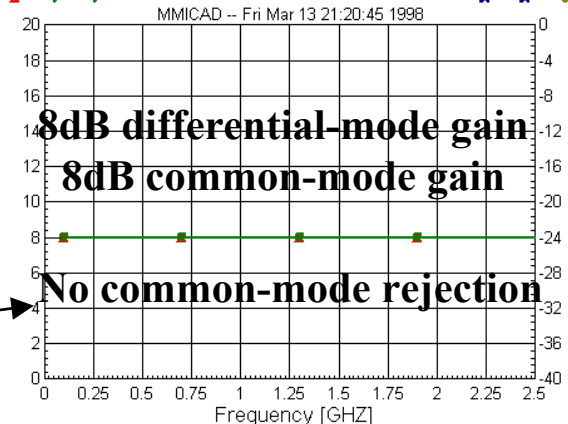
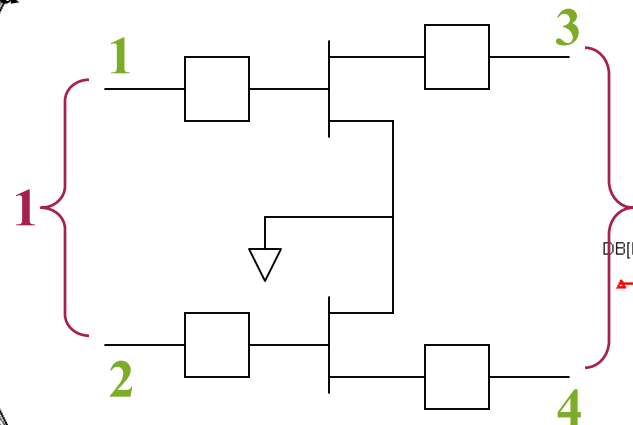
Symmetric Circuit, Zero Ground Z



Single-ended

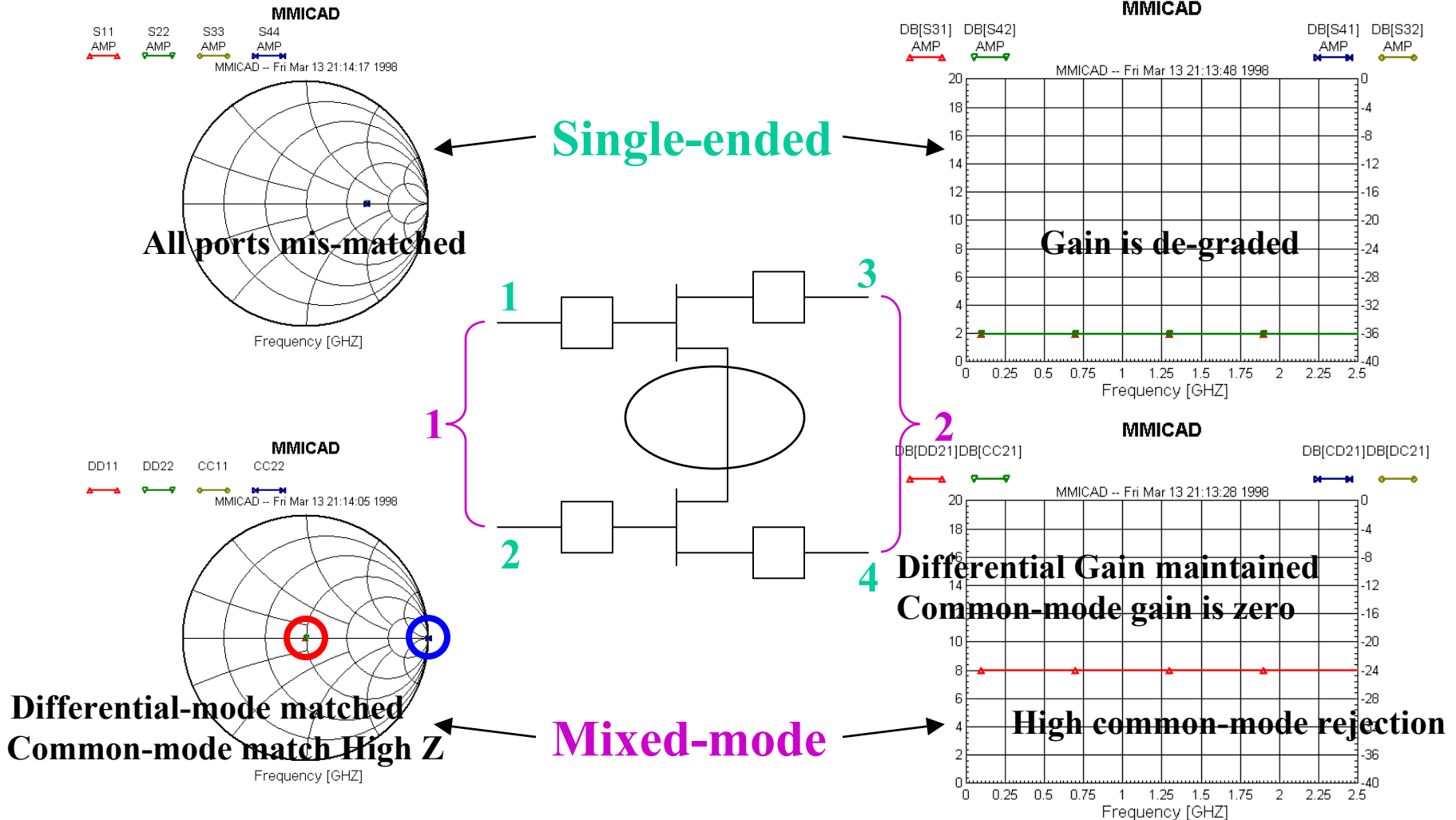


Mixed-mode



RF Balanced Device Characterization

Symmetric Circuit, Infinite Ground Z



RF Balanced Device Characterization

Agenda

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RF Balanced Device Characterization

Conclusion

- **Balanced Devices present many new test challenges**
- **Mixed-mode S-parameters provide comprehensive characterization (D-D, C-C, D-C, C-D) of balanced ports/devices**
- **Traditional S-parameters may be misleading and lead to lower performance designs**
- **Dedicated balanced measurement solutions include sophisticated calculations and calibration**



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